NSN 5961-01-210-5283

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-210-5283 **Inclosure Material:** Plastic **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.165 inches **Overall Width:** 0.205 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, collector-to-emitter, base open and 25.0 breakdown voltage, collector-to-base, emitter open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 100.00 nanoamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 360.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 225.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No